

PJQ5433E

30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

-68 A

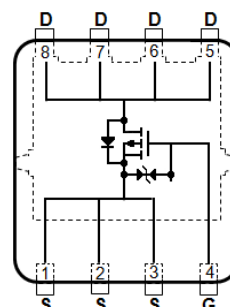
Features

- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-20A<8.4m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-10A<13.5m\Omega$
- 100% UIS tested
- Reliable and Rugged
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060X-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.087 grams

DFN5060X-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-30	V
Gate-Source Voltage		V_{GS}	± 25	
Continuous Drain Current ^(Note 3)	$T_C=25^\circ\text{C}$	I_D	-68	A
	$T_C=100^\circ\text{C}$		-43	
Pulsed Drain Current ^(Note 1)	$T_C=25^\circ\text{C}$	I_{DM}	-215	
Power Dissipation	$T_C=25^\circ\text{C}$	P_D	62.5	W
	$T_C=100^\circ\text{C}$		25	
Continuous Drain Current ^(Note 4)	$T_A=25^\circ\text{C}$	I_D	-14.4	A
	$T_A=70^\circ\text{C}$		-11.5	
Power Dissipation	$T_A=25^\circ\text{C}$	P_D	2.8	W
	$T_A=70^\circ\text{C}$		1.8	
Single Pulse Avalanche Energy ^(Note 5)		E_{AS}	121	mJ
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ\text{C}$
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	2	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	45	

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.7	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-20A	-	6.7	8.4	mΩ
		V _{GS} =-4.5V, I _D =-10A	-	10.4	13.5	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±25V, V _{DS} =0V	-	-	±10	uA
		V _{GS} =±10V, V _{DS} =0V	-	-	±1	
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =-24V, I _D =-20A, V _{GS} =-10V	-	54	-	nC
Gate-Source Charge	Q _{gs}		-	6	-	
Gate-Drain Charge	Q _{gd}		-	17	-	
Input Capacitance	C _{iss}	V _{DS} =-25V, V _{GS} =0V, f=1MHz	-	2310	-	pF
Output Capacitance	C _{oss}		-	332	-	
Reverse Transfer Capacitance	C _{rss}		-	256	-	
Gate resistance	R _g	f=1MHz	-	2.3	-	Ω
Turn-On Delay Time	td _(on)	V _{DS} =-24V, I _D =-20A, V _{GS} =-10V, R _G =3Ω (Note 2)	-	11	-	ns
Turn-On Rise Time	tr		-	9	-	
Turn-Off Delay Time	td _(off)		-	37	-	
Turn-Off Fall Time	tf		-	21	-	
Drain-Source Diode						
Diode Forward Current	I _s	T _C =25°C	-	-	-68	A
Pulsed Diode Forward Current	I _{SM}		-	-	-215	
Diode Forward Voltage	V _{SD}	I _S =-20A, V _{GS} =0V	-	-0.85	-1.3	V
Reverse Recovery Time	T _{rr}	V _{GS} =0V, I _S =-20A	-	22	-	ns
Reverse Recovery Charge	Q _{rr}	dI _S /dt=100A/us	-	10	-	nC

NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. The test condition is L=0.5mH, I_{AS}=-22A, V_{DD}=-30V, V_{GS}=-10V, Starting T_J=25°C.
6. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

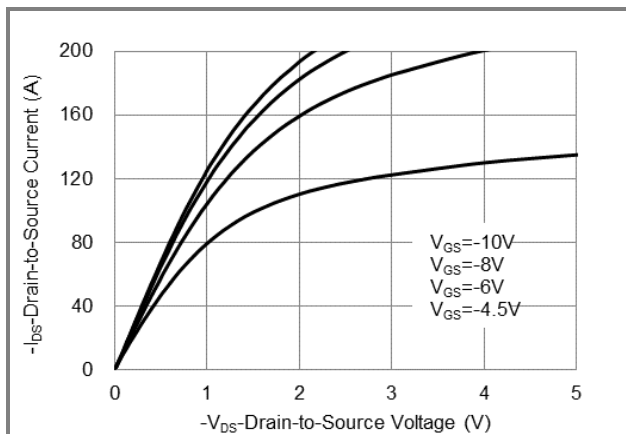


Fig.1 On-Region Characteristics

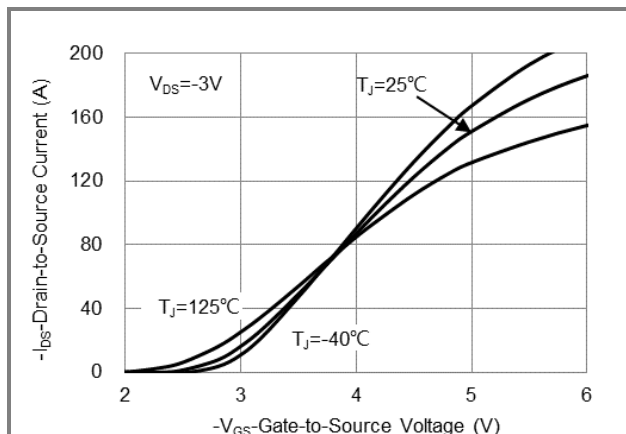


Fig.2 Transfer Characteristics

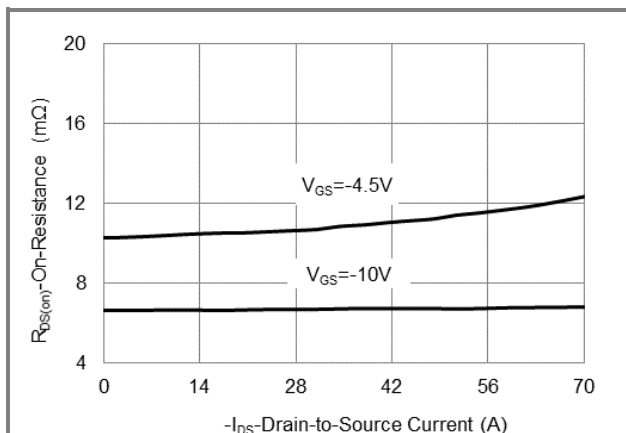


Fig.3 On-Resistance vs. Drain Current

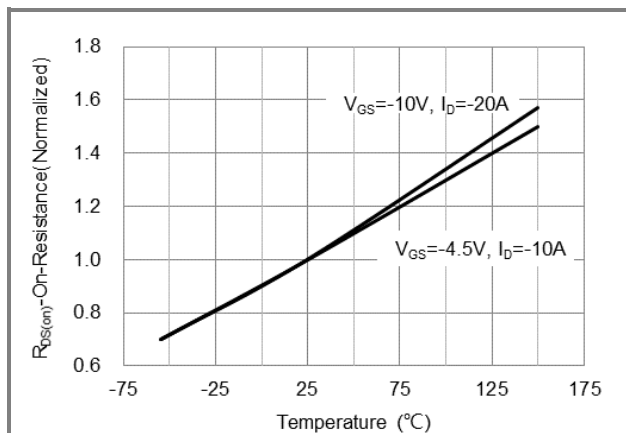


Fig.4 On-Resistance vs. Junction temperature

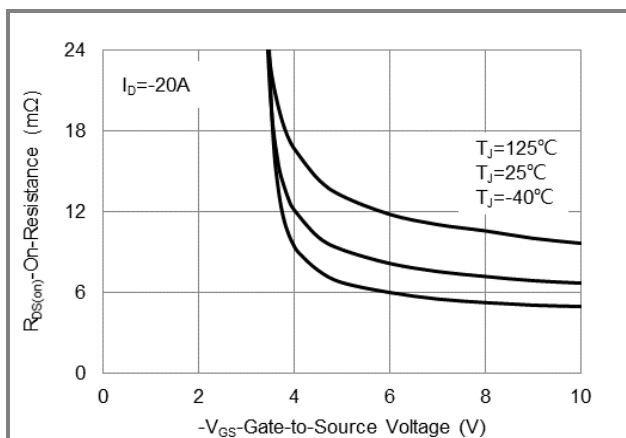


Fig.5 On-Resistance Variation with V_{GS}

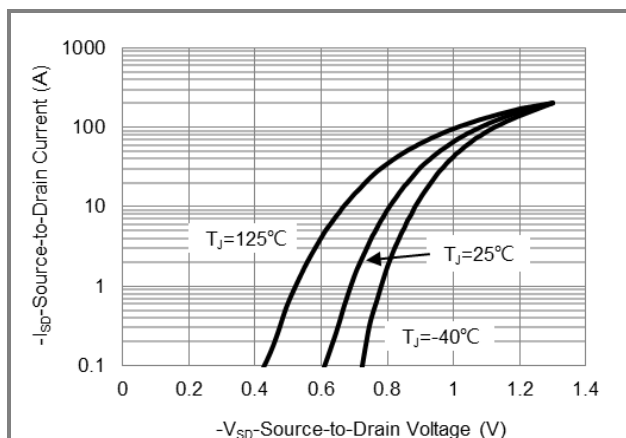
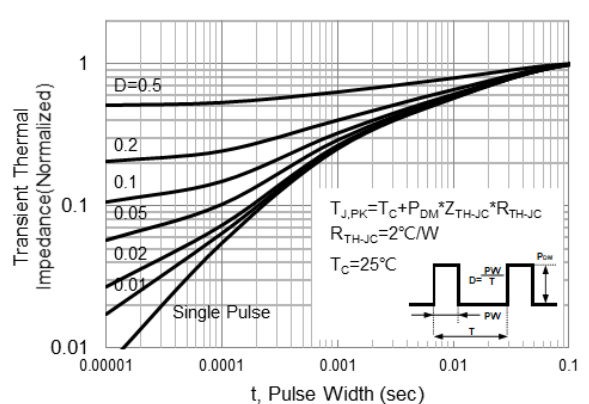
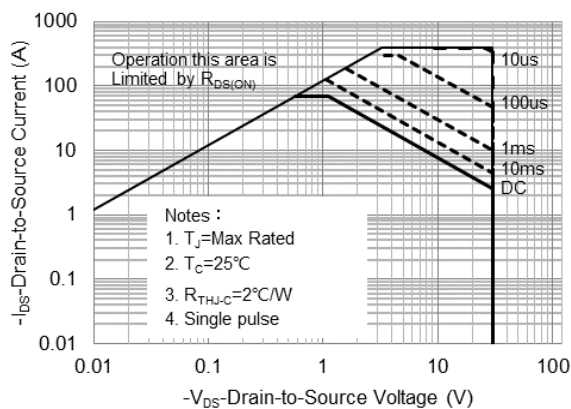
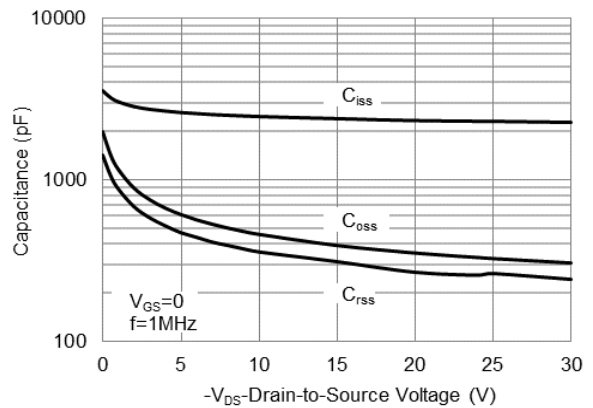
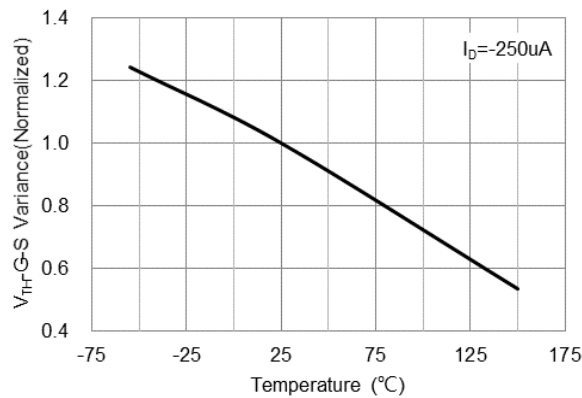
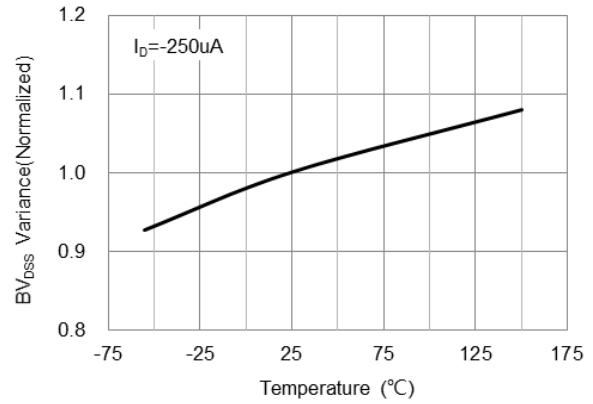
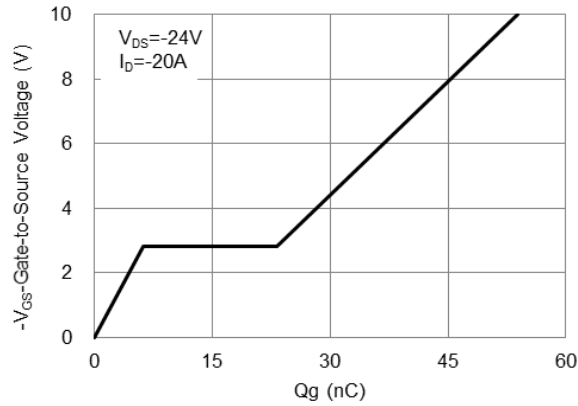


Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES



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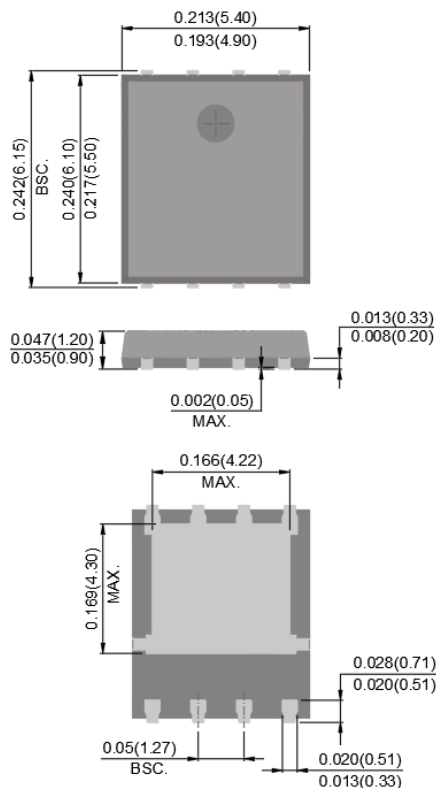
Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ5433E	DFN5060X-8L	3K pcs / 13" reel	Q5433E

Packaging Information & Mounting Pad Layout

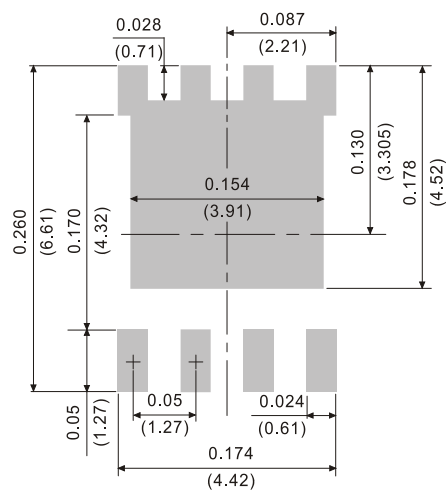
DFN5060X-8L Dimension

Unit: inch(mm)



DFN5060X-8L Pad Layout

Unit: inch(mm)



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